

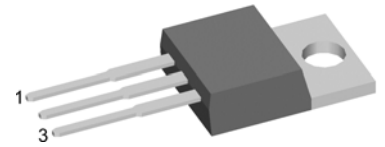
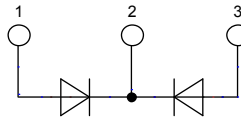
Sonic Fast Recovery Diode

High Performance Fast Recovery Diode
 Low Loss and Soft Recovery
 Common Cathode

$V_{RRM} = 600\text{ V}$
 $I_{FAV} = 2 \times 20\text{ A}$
 $t_{rr} = 40\text{ ns}$

Part number

DHG 40 C 600 PB



Backside: cathode

Features / Advantages:

- Planar passivated chips
- Very low leakage current
- Very short recovery time
- Improved thermal behaviour
- Very low I_{rm} -values
- Very soft recovery behaviour
- Avalanche voltage rated for reliable operation
- Soft reverse recovery for low EMI/RFI
- Low I_{rm} reduces:
 - Power dissipation within the diode
 - Turn-on loss in the commutating switch

Applications:

- Antiparallel diode for high frequency switching devices
- Antisaturation diode
- Snubber diode
- Free wheeling diode
- Rectifiers in switch mode power supplies (SMPS)
- Uninterruptible power supplies (UPS)

Package:

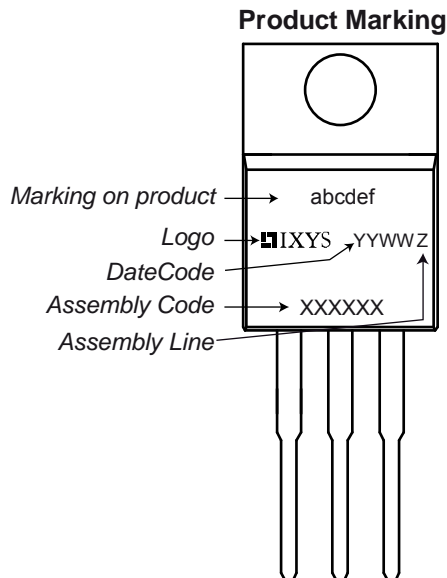
- Housing: TO-220
- Industry standard outline
- Epoxy meets UL 94V-0
- RoHS compliant

Ratings

Symbol	Definition	Conditions	Ratings			Unit
			min.	typ.	max.	
V_{RRM}	max. repetitive reverse voltage				600	V
I_R	reverse current	$V_R = 600\text{ V}$			25	μA
		$V_R = 600\text{ V}$			1.5	mA
V_F	forward voltage	$I_F = 20\text{ A}$			2.25	V
		$I_F = 40\text{ A}$			3.17	V
		$I_F = 20\text{ A}$			2.20	V
		$I_F = 40\text{ A}$			3.23	V
I_{FAV}	average forward current	rectangular $d = 0.5$			20	A
V_{F0}	threshold voltage	} for power loss calculation only			1.12	V
r_F	slope resistance				49	m Ω
R_{thJC}	thermal resistance junction to case				0.90	K/W
T_{VJ}	virtual junction temperature		-55		150	$^{\circ}\text{C}$
P_{tot}	total power dissipation				140	W
I_{FSM}	max. forward surge current	$t = 10\text{ ms}$ (50 Hz), sine			150	A
I_{RM}	max. reverse recovery current				8	A
		$I_F = 20\text{ A}; V_R = 300\text{ V}$			12	A
t_{rr}	reverse recovery time	$-di_F/dt = 450\text{ A}/\mu\text{s}$			40	ns
					60	ns
C_J	junction capacitance	$V_R = 400\text{ V}; f = 1\text{ MHz}$			13	pF

Symbol	Definition	Conditions	Ratings			Unit
			min.	typ.	max.	
I_{RMS}	RMS current	per terminal ¹⁾			35	A
R_{thCH}	thermal resistance case to heatsink			0.50		K/W
T_{stg}	storage temperature		-55		150	°C
Weight				2		g
M_D	mounting torque		0.4		0.6	Nm
F_C	mounting force with clip		20		60	N

¹⁾ I_{RMS} is typically limited by the pin-to-chip resistance (1); or by the current capability of the chip (2).
 In case of (1) and a common cathode/anode configuration with a non-isolated backside, the current capability can be increased by connecting the backside.



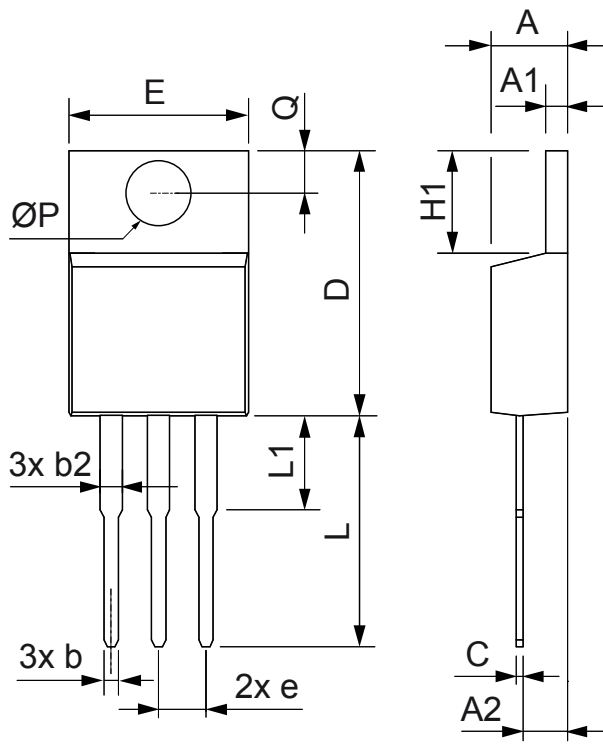
Part number

- D = Diode
- H = Sonic Fast Recovery Diode
- G = extreme fast
- 40 = Current Rating [A]
- C = Common Cathode
- 600 = Reverse Voltage [V]
- PB = TO-220AB (3)

Ordering	Ordering Number	Marking on Product	Delivery Mode	Quantity	Code No.
Standard	DHG 40 C 600 PB	DHG40C600PB	Tube	50	504948

Similar Part	Package	Voltage Class
DHG40C600HB	TO-247AD (3)	600

Outlines TO-220



Dim.	Millimeter		Inches	
	Min.	Max.	Min.	Max.
A	4.32	4.82	0.170	0.190
A1	1.14	1.39	0.045	0.055
A2	2.29	2.79	0.090	0.110
b	0.64	1.01	0.025	0.040
b2	1.15	1.65	0.045	0.065
C	0.35	0.56	0.014	0.022
D	14.73	16.00	0.580	0.630
E	9.91	10.66	0.390	0.420
e	2.54	BSC	0.100	BSC
H1	5.85	6.85	0.230	0.270
L	12.70	13.97	0.500	0.550
L1	2.79	5.84	0.110	0.230
ØP	3.54	4.08	0.139	0.161
Q	2.54	3.18	0.100	0.125

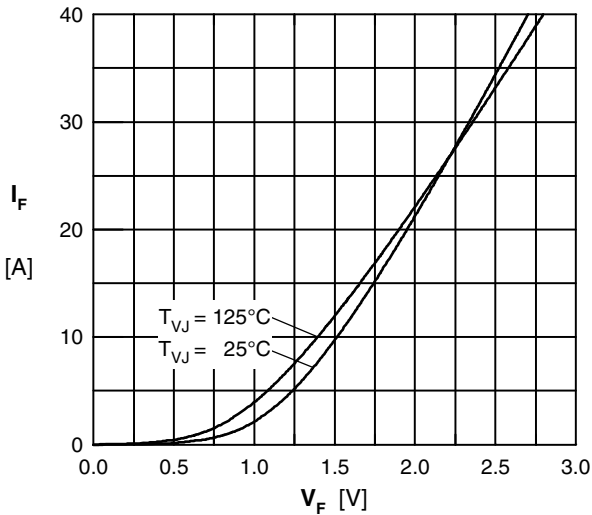


Fig. 1 Typ. Forward current versus V_F

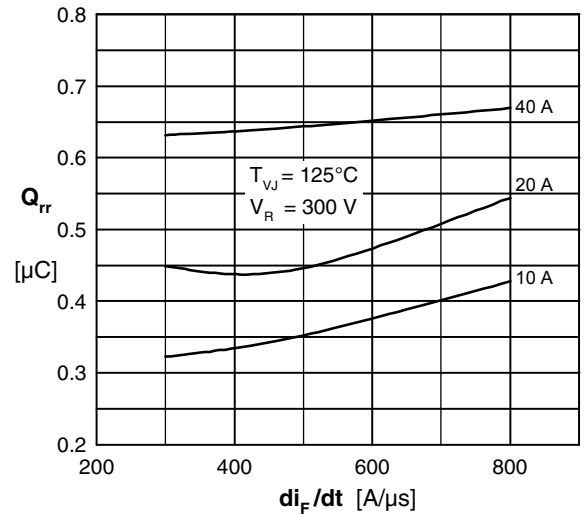


Fig. 2 Typ. reverse recov.charge Q_{rr} vs. di/dt

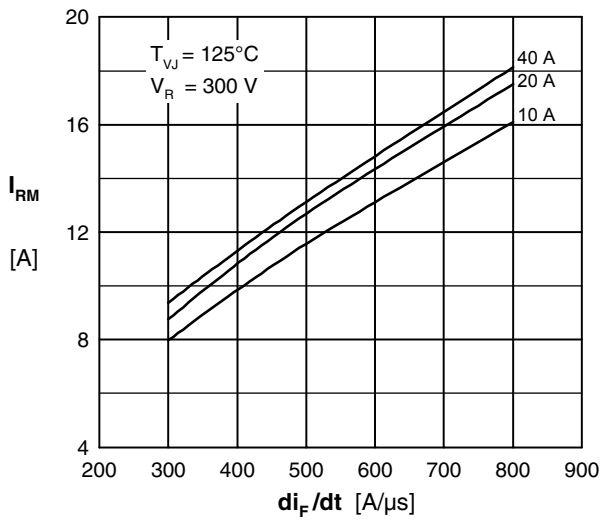


Fig. 3 Typ. peak reverse current I_{RM} vs. di/dt

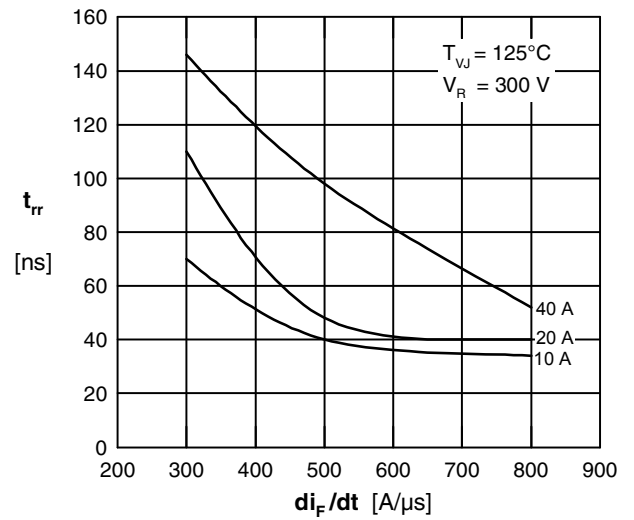


Fig. 4 Typ. recovery time t_{rr} versus di/dt

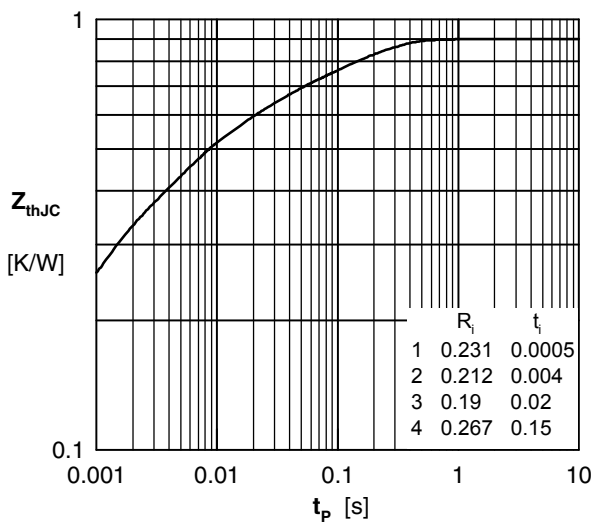


Fig. 5 Typ. transient thermal impedance